



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
001/	20.2mΩ @ V _{GS} = 4.5V	21A
20V	23.5mΩ @ V _{GS} = 2.5V	14A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- **Battery Management Application**
- **Power Management Functions**
- **DC-DC Converters**

U-DFN2030-6 (Type B)





Bottom View

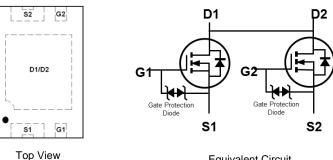
DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low Gate Threshold Voltage •
- Low On-Resistance
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: U-DFN2030-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 .
- Terminal Connections NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.012 grams (Approximate)



Pin Configuration

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2024UFU-7	U-DFN2030-6 (Type B)	3000/Tape & Reel
DMN2024UFU-13	U-DFN2030-6 (Type B)	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes: 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



R28 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 for 2020) WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	20	V		
Gate-Source Voltage			V _{GSS}	±10	V
Continuous Drain Current (Note 6) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	7.5 6	A
	Steady State	Tc = +25°C Tc = +70°C	ID	21 17	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	IDM	50	A		
Maximum Continuous Body Diode Forward Current	ls	0.6	A		
Avalanche Current (Note 7) L = 0.1mH			I _{AS}	12	А
Avalanche Energy (Note 7) L = 0.1mH			Eas	8	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.81	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	155	°C/W	
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.71	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	73	°C M/	
Thermal Resistance, Junction to Case (Note 6)	Steady State	Rejc	8.9	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Symbol		Тур	IVIAN	Unit		
Drain-Source Breakdown Voltage	BVDSS	20	_	_	V	Vgs = 0V, Id = 250µA	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$		_	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	1000						
Gate Threshold Voltage	V _{GS(TH)}	0.35	_	0.95	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Quartia Dania Que Daniatara a			11.2	20.2		VGS = 4.5V, ID = 6.5A	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	13.2	23.5	mΩ	V _{GS} = 2.5V, I _D = 5.5A	
Diode Forward Voltage	Vsd	_	0.7	1.0	V	$V_{GS} = 0V$, $I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)	•					· ·	
Input Capacitance	Ciss	_	647	_	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	—	78	—	pF		
Reverse Transfer Capacitance	Crss	_	38	_	pF		
Gate Resistance	Rg	_	400	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	QG	—	6.5	—	nC		
Total Gate Charge (V _{GS} = 10V)	QG	_	14.8	_	nC		
Gate-Source Charge	Qgs	_	1.1	_	nC	$V_{DS} = 10V, I_{D} = 6.5A$	
Gate-Drain Charge	Q _{GD}	_	1.7	_	nC	7	
Turn-On Delay Time	td(on)	_	140	_	ns		
Turn-On Rise Time	tR	_	1024	_	ns	V _{DS} = 10V, V _{GS} = 4.5V, R _G = 6Ω, R _L = 10Ω, I _D = 1A	
Turn-Off Delay Time	t _{D(OFF)}	_	434	_	ns		
Turn-Off Fall Time	tF	_	245	_	ns		
Reverse Recovery Time	trr	_	149	_	ns		
Reverse Recovery Charge	QRR	_	647	_	nC	— I _F = 1A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.



DMN2024UFU

T_J = 85°C

= 25°C

1.5

2

T_J = -55°C

6

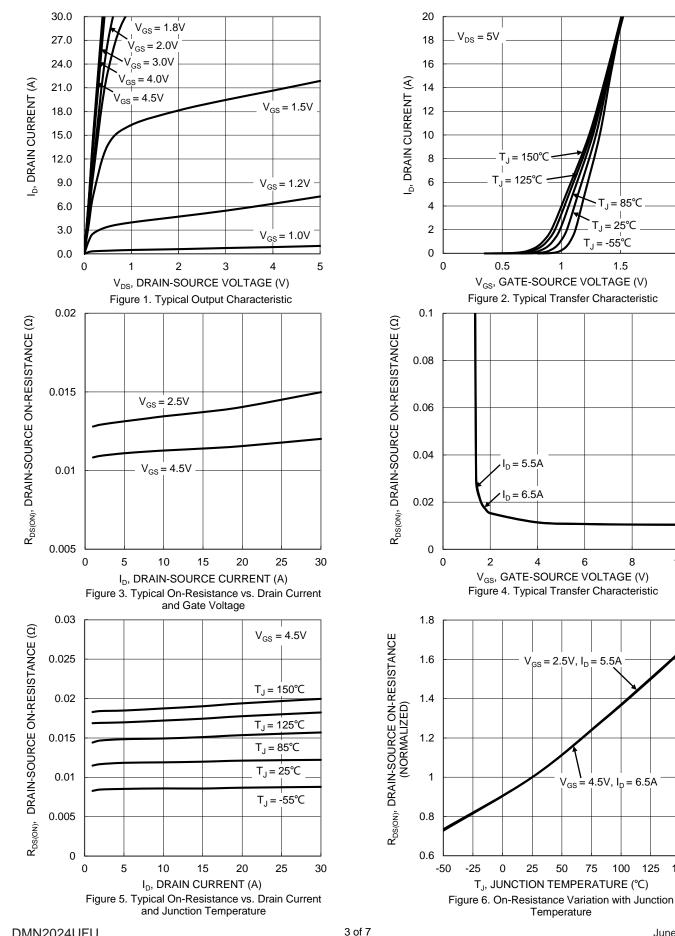
75

100

125

8

10

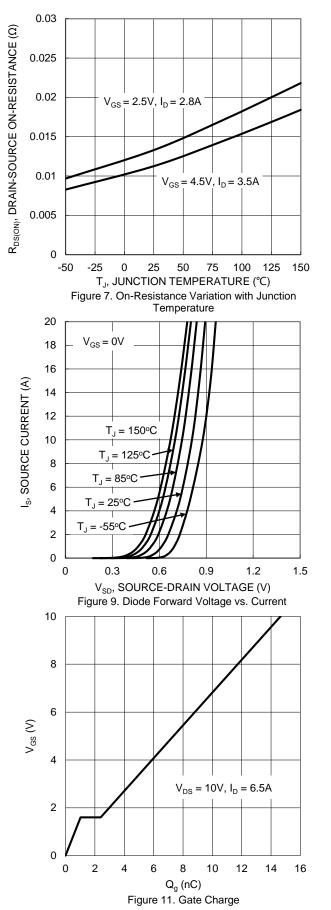


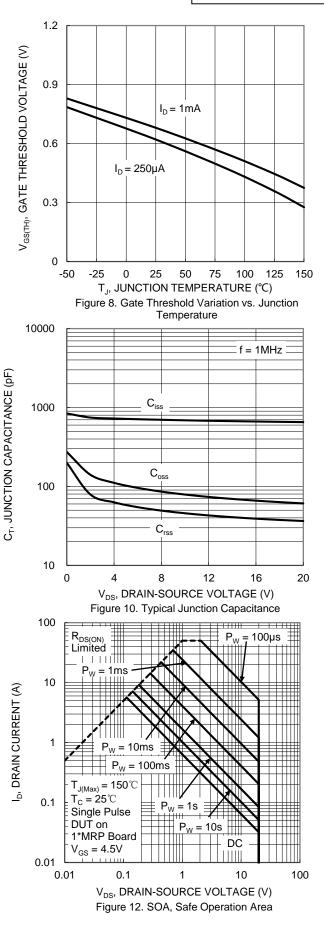
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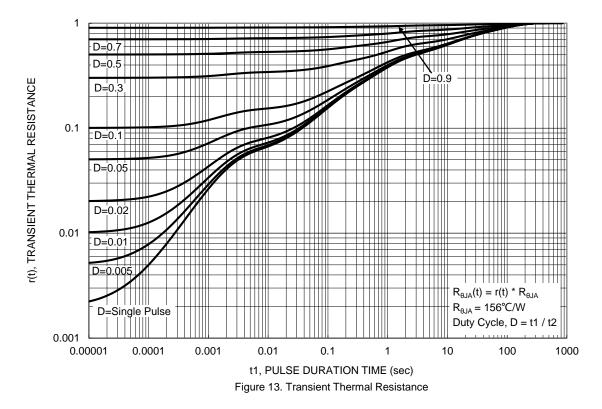








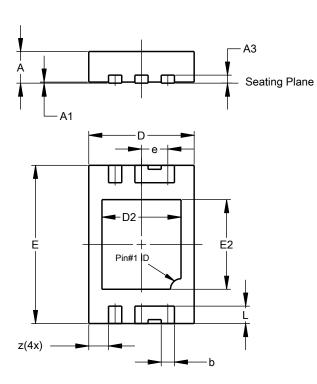






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



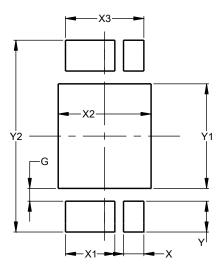
U-DFN2030-6 (Type B)					
Dim	Min	Max	Тур		
Α	0.55	0.65	0.60		
A1	0.00	0.05	0.02		
A3			0.15		
b	0.20	0.30	0.25		
D	1.95	2.05	2.00		
D2	1.40	1.60	1.50		
E	2.95	3.05	3.00		
E2	1.65	1.75	1.70		
е			0.50		
L	0.28	0.38	0.33		
z			0.375		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2030-6 (Type B)

U-DFN2030-6 (Type B)



Dimensions	Value
Dimensions	(in mm)
G	0.220
Х	0.350
X1	0.850
X2	1.600
X3	1.350
Y	0.530
Y1	1.800
Y2	3.300



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